



ON Semiconductor®

BD135 / 137 / 139

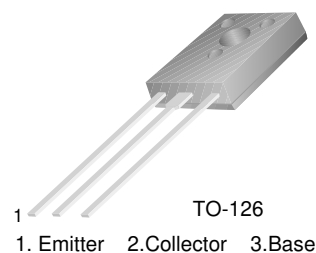
NPN Epitaxial Silicon Transistor

Features

- Complement to BD136, BD138 and BD140 respectively

Applications

- Medium Power Linear and Switching



Ordering Information

Part Number	Marking	Package	Packing Method
BD13516S	BD135-16	TO-126 3L	Bulk
BD1356STU	BD135-6		Rail
BD13510STU	BD135-10		
BD13516STU	BD135-16		
BD13716STU	BD137-16		
BD13710STU	BD137-10		Bulk
BD13716S	BD137-16		Rail
BD13916STU	BD139-16		Bulk
BD13910S	BD139-10		Rail
BD13916S	BD139-16		
BD1396STU	BD139-6		
BD13910STU	BD139-10		

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter		Value	Units
V_{CBO}	Collector-Base Voltage	BD135	45	V
		BD137	60	
		BD139	80	
V_{CEO}	Collector-Emitter Voltage	BD135	45	V
		BD137	60	
		BD139	80	
V_{EBO}	Emitter-Base Voltage		5	V
I_C	Collector Current (DC)		1.5	A
I_{CP}	Collector Current (Pulse)		3.0	A
I_B	Base Current		0.5	A
P_C	Device Dissipation	$T_C = 25^\circ\text{C}$	12.5	W
		$T_A = 25^\circ\text{C}$	1.25	W
T_J	Junction Temperature		150	$^\circ\text{C}$
T_{STG}	Storage Temperature		- 55 to +150	$^\circ\text{C}$

Electrical Characteristics

Values are at $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter		Test Condition	Min.	Typ.	Max.	Units
$V_{CEO(sus)}$	Collector-Emitter Sustaining Voltage	BD135	$I_C = 30\text{ mA}, I_B = 0$	45			V
		BD137		60			
		BD139		80			
I_{CBO}	Collector Cut-off Current		$V_{CB} = 30\text{ V}, I_E = 0$			0.1	A
I_{EBO}	Emitter Cut-off Current		$V_{EB} = 5\text{ V}, I_C = 0$			10	A
h_{FE1}	DC Current Gain		$V_{CE} = 2\text{ V}, I_C = 5\text{ mA}$	25			
h_{FE2}			$V_{CE} = 2\text{ V}, I_C = 0.5\text{ A}$	25			
h_{FE3}			$V_{CE} = 2\text{ V}, I_C = 150\text{ mA}$	40		250	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage		$I_C = 500\text{ mA}, I_B = 50\text{ mA}$			0.5	V
$V_{BE(on)}$	Base-Emitter On Voltage		$V_{CE} = 2\text{ V}, I_C = 0.5\text{ A}$			1	V

h_{FE} Classification

Classification	6	10	16
h_{FE3}	40 ~ 100	63 ~ 160	100 ~ 250

Typical Performance Characteristics

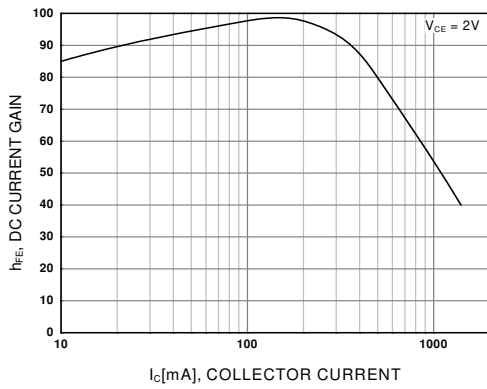


Figure 1. DC current Gain

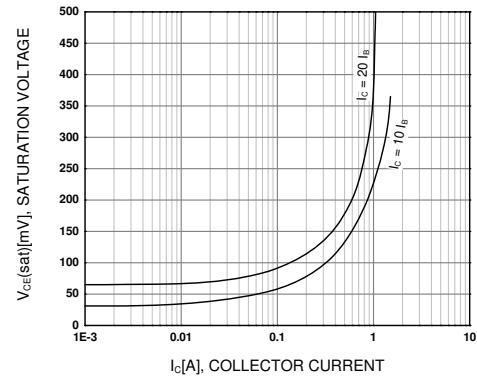


Figure 2. Collector-Emitter Saturation Voltage

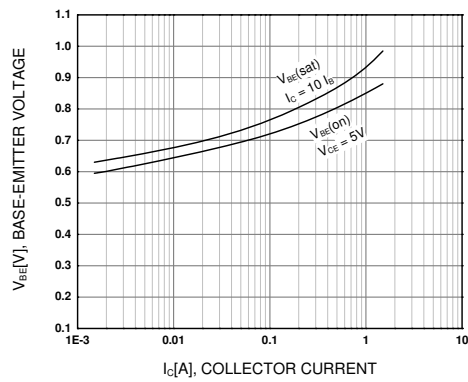


Figure 3. Base-Emitter Voltage

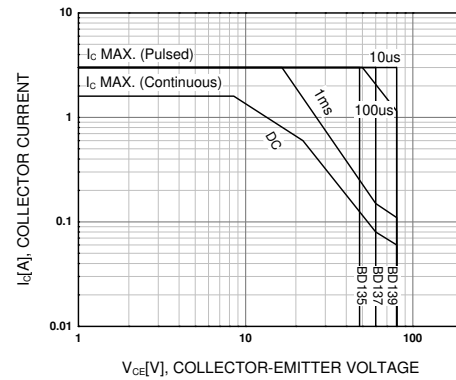


Figure 4. Safe Operating Area

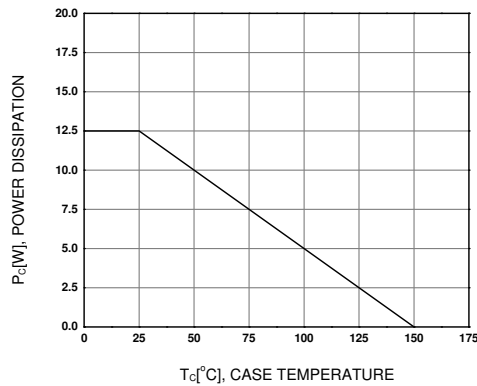
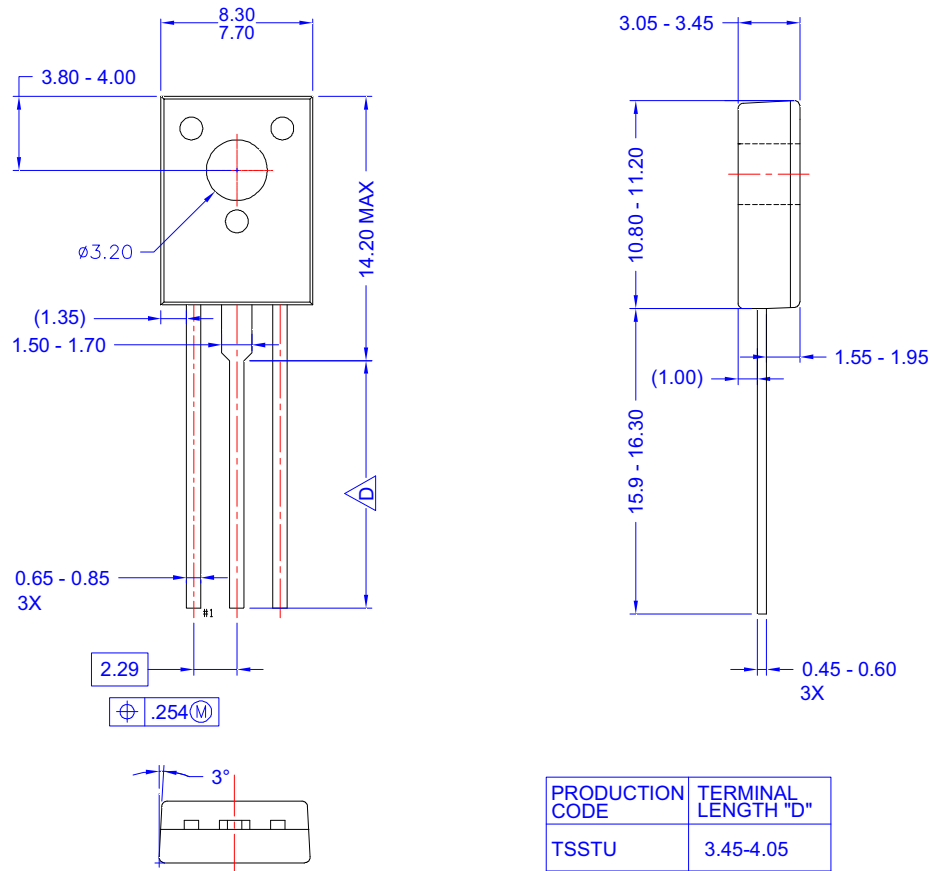


Figure 5. Power Derating

Physical Dimensions

TO-126 3L



NOTES:

- THIS PACKAGE DOES NOT COMPLY TO ANY CURENT PACKAGING STANDARD.
- ALL DIMENSIONS ARE IN MILLIMETERS.
- DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- FOR TERMINAL LENGTH SEE TABLE
- DRAWING FILE NAME AND REVISION : MKT-TO126AArev1

Figure 6. TO-126 (SOT-32) UNIFIED DRAWING (TSTU, TSSTU, STANDARD)

Package drawings are provided as a service to customers considering ON Semiconductor components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a ON Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of ON Semiconductor's worldwide terms and conditions, specifically the warranty therein, which covers ON Semiconductor products.

ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor
19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
USA/Canada

Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910

Japan Customer Focus Center
Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: <http://www.onsemi.com/orderlit>

For additional information, please contact your local
Sales Representative